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LME49722 Low Noise, High Performance, High Fidelity Dual Audio Operational Amplifier

Check for Samples: LME49722

FEATURES

- Easily Drives 600Ω Loads
- Optimized for Superior Audio Signal Fidelity
- Output Short Circuit Protection
- PSRR and CMRR Exceed 120dB (typ)

APPLICATIONS

- Ultra High Quality Audio Amplification
- High Fidelity Preamplifiers, Phono Preamps, and Multimedia
- High Performance Professional Audio
- High Fidelity Equalization and Crossover Networks with Active Filters
- High Performance Line Drivers and Receivers
- Low Noise Industrial Applications Including Test, Measurement, and Ultrasound

DESCRIPTION

The LME49722 is part of the ultra-low distortion, low noise, high slew rate operational amplifier series optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49722 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LME49722 combines extremely low voltage noise density (1.9nV/√Hz) rate with vanishingly low THD+N (0.00002%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49722 has a high slew rate of ±22V/µs and an output current capability of ±28mA. Further, dynamic range is maximized by an output stage that drives $2k\Omega$ loads to within 1V of either power supply voltage.

The LME49722 has a wide supply range of ±2.5V to ±18V. Over this supply range the LME49722 maintains excellent common-mode and power supply rejection, and low input bias current. This Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF with gain value greater than 2. Directly interchangeable with LME49720, LM4562 and LME49860 for similar operating voltages.

Table 1. KEY SPECIFICATIONS

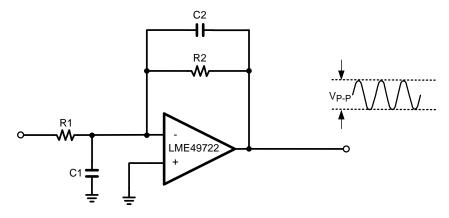
| | | VALUE | UNIT |
|--|-------------------|--------------|-----------------------------|
| Wide Operating Voltage Range | | ±2.5V to ±18 | V |
| Equivalent Noise (Frequency = 1kHz) | | 1.9 | nV/\sqrt{Hz} (typ) |
| Equivalent Noise (Frequency = 10Hz) | | 2.8 | nV/√ Hz (typ) |
| PSRR | | 120 | dB (typ) |
| Slew Rate | | ±22 | V/µs (typ) |
| THD+N | $R_L = 2k\Omega$ | 0.00002 | % (typ) |
| $(A_V = 1, V_{OUT} = 3V_{RMS}, f_{IN} = 1kHz)$ | $R_L = 600\Omega$ | 0.00002 | % (typ) |
| Open Loop Gain ($R_L = 600\Omega$) | | 135 | dB (typ) |
| Input Bias Current | | 50 | nA (typ) |
| Voltage Offset | | ±0.02 | mV (typ) |

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Typical Application



 f_{MAX} = > 300 kHz for Vp-p = 20V, R2 C2 \approx R1 C1

Figure 1. Wide Bandwidth Low Noise Low Drift Amplifier

Connection Diagram

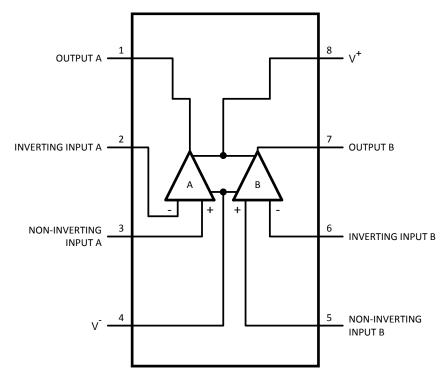


Figure 2. 8-Lead SOIC See D Package

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1)(2)(3)

| | 38V |
|-------------------------------------|----------------|
| | −65°C to 150°C |
| Input Voltage | |
| Output Short Circuit ⁽⁴⁾ | |
| ESD Susceptibility ⁽⁵⁾ | |
| ESD Susceptibility ⁽⁶⁾ | |
| | 150°C |
| θ_{JA} | 154°C/W |
| θ_{JC} | 27°C/W |
| | |

- (1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.
- The Electrical Characteristics tables list specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not
- If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX} , θ_{JA} , and the ambient temperature, T_A . The maximum allowable power dissipation is $P_{DMAX} = (T_{JMAX} - T_A) / \theta_{JA}$ or the number given in Absolute Maximum Ratings, whichever is lower. For the LME49722, $T_{JMAX} = 150^{\circ}$ C and the typical θ_{JC} is 27°C/W. Human body model, applicable std. JESD22-A114C.
- Machine model, applicable std. JESD22-A115-A.

Operating Ratings

| Temperature Range | $T_{MIN} \le T_A \le T_{MAX}$ | -40°C ≤ T _A ≤ 85°C |
|----------------------|-------------------------------|-------------------------------|
| Supply Voltage Range | | ±2.5V ≤ V _S ≤ ±18V |

Product Folder Links: LME49722



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Electrical Characteristics for the LME49722 (1)(2)

The following specifications apply for $V_S = \pm 15 V$ and $\pm 18 V$, $R_L = 2 k \Omega$, $f_{IN} = 1 k Hz$ unless otherwise specified. Limits apply for $T_A = 25^{\circ}C$,

| Comple al | Parameter | Conditions | LME4 | LME49722 | |
|---|--|---|------------------------|--|------------------------------------|
| Symbol | | | Typical ⁽³⁾ | Limit (4) | Units (Limits) |
| THD+N | Total Harmonic Distortion + Noise | $\begin{aligned} A_V &= 1, V_{OUT} = 3V_{rms} \\ R_L &= 2k\Omega \\ R_L &= 600\Omega \end{aligned}$ | 0.00002 0.00002 | 0.00009 | % % (max) |
| IMD | Intermodulation Distortion | $A_V = 1$, $V_{OUT} = 3V_{RMS}$ Two-tone, 60Hz & 7kHz 4:1 | 0.00002 | | % |
| GBWP | Gain Bandwidth Product | f _{IN} = 100kHz | 55 | 45 | MHz (min) |
| SR | Slew Rate | $A_V = 1$, $V_{OUT} = 10V_{P-P}$ | ±22 | ±15 | V/µs (min) |
| FPBW | Full Power Bandwidth | V _{OUT} = 1V _{P-P} , -3dB referenced to output magnitude at f = 1kHz | 12 | | MHz |
| t _s | Settling time | $A_V = -1$, 10V step, $C_L = 100pF$ 0.1% error range | 1.2 | | μs |
| e _{INV} | Equivalent Input Voltage Noise | f _{BW} = 20Hz to 20kHz | 0.25 | 0.35 | μV _{RMS} (max) |
| e _N Equivalent Input Voltage Density | $f= 1kHz$ $V_S = \pm 15V$ $V_S = \pm 18V$ | 1.9 1.9 | 2.5 | nV√Hz nV√Hz (max) | |
| | f = 10Hz $V_S = \pm 15V$ $V_S = \pm 18V$ | 2.8 3.2 | | nV√ <u>Hz</u> nV√Hz | |
| In | Current Noise Density | f = 1kHz f = 10Hz | 2.6 6 | | pA /√ Hz pA /√ Hz |
| Vos | Offset Voltage | V _{CM} = 0V | ±0.02 | ±0.7 | mV (max) |
| PSRR | Power Supply Rejection Ratio | $\Delta V_{S} = 20V^{(5)}$ | 120 | 110 | dB (min) |
| ISO _{CH-CH} | Channel-to-Channel Isolation | $f_{IN} = 1kHz$ $f_{IN} = 20kHz$ | 136 135 | | dB dB |
| I _B | Input Bias Current | $V_{CM} = 0V$ $V_{S} = \pm 15V$ $V_{S} = \pm 18V$ | 50 53 | 200 | nA nA (max) |
| ΔI _{OS} /ΔTe mp | Input Bias Current Drift vs Temperature | -40°C ≤ T _A ≤ 85°C | 0.1 | | nA/°C |
| I _{OS} | Input Offset Current | $V_{CM} = 0V$ $V_{S} = \pm 15V$ $V_{S} = \pm 18V$ | 25 32 | 100 | nA nA (max) |
| V _{IN-CM} Common-Mode Input Voltage Rang | Common Mada Innut Valtage Bange | V _S = ±15V | +14.0 -13.9 | $(V_{CC)} - 2.0$ $(V_{EE}) + 2.0$ | V (min) V (min) |
| | Common-wode input voltage Range | V _S = ±18V | +17.0 -16.9 | (V _{CC}) – 2.0 (V _{EE}) + 2.0 | V (min) V (min) |
| CMRR | Common-Mode Rejection | -10V ≤ V _{CM} ≤ 10V | 128 | 110 | dB (min) |
| Z _{IN} | Differential Input Impedance | | 30 | | kΩ |
| Z _{CM} | Common Mode Input Impedance | -10V ≤ V _{CM} ≤ 10V | 1000 | | ΜΩ |
| A _{VOL} | Open Loop Voltage Gain | | 135 140 140 | 120 | dB dB dB |

[&]quot;Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

Product Folder Links: LME49722

The Electrical Characteristics tables list specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not

Typical values represent most likely parametric norms at T_A = +25°C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.

Datasheet min/max specification limits are specified by test or statistical analysis.

PSRR is measured as follow: V_{OS} is measured at two supply voltages, $\pm 5V$ and $\pm 15V$. PSRR = $|20log(\Delta V_{OS}/\Delta V_S)|$. (5)



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Electrical Characteristics for the LME49722 (1)(2) (continued)

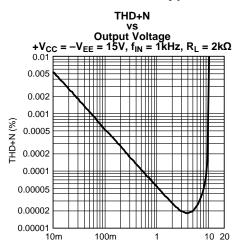
The following specifications apply for $V_S = \pm 15 V$ and $\pm 18 V$, $R_L = 2 k \Omega$, $f_{IN} = 1 k Hz$ unless otherwise specified. Limits apply for $T_A = 25 \, ^{\circ} C$,

| Symbol | Parameter | | LME4 | LME49722 | |
|--------------------------------------|--|--|-----------------------------|---|---|
| | | Conditions | Typical ⁽³⁾ | Limit (4) | (Limits) |
| V _{OM} Output Voltage Swing | | $V_S = \pm 15V$ $R_L = 600\Omega$ $R_L = 2k\Omega$ $R_L = 10k\Omega$ | +13.7/-14 ±14.0 ±14.1 | | V _{PEAK} V _{PEAK} V _{PEAK} |
| | $V_S = \pm 18V$ $R_L = 600\Omega$ $R_L = 2k\Omega$ $R_L = 10k\Omega$ | +16.6/-16.8 ±17.0 ±17.1 | ±15.5 | V _{PEAK} (min) V _{PEAK} V _{PEAK} | |
| I _{OUT} | Output Current | $R_L = 600\Omega$ $V_S = \pm 15V$ $V_S = \pm 18V$ | ±23 ±27.6/–28 | ±23 | mA mA (min) |
| I _{OUT-CC} | Short Circuit Current | Sink to Source | +43 -40 | | mA mA |
| Z _{OUT} | Output Impedance | f _{IN} = 10kHz Closed-Loop Open-Loop | 0.01 13 | | Ω |
| I _S | Total Quiescent Power Supply Current | $I_{OUT} = 0mA$ $V_S = \pm 15V$ $V_S = \pm 18V$ | 12.1 12.3 | 16 | mA mA (max) |

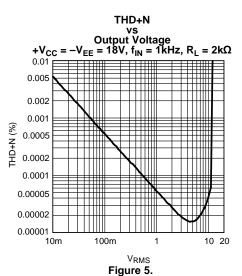
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Typical Performance Characteristics



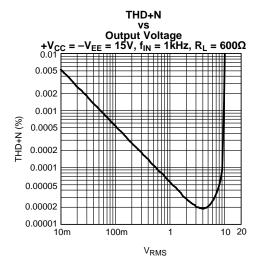
 V_{RMS} Figure 3.



Frequency 15V, $V_0 = 3V_{RMS}$, $R_L = 2k\Omega$ ·V_{EE} = 0.0005 0.0002 (%) N+QHL 0.0001 0.00005 0.00002 0.00001 50 100 200 500 1k 2k 20 5k 10k 20k FREQUENCY (Hz)

Figure 7.

THD+N



Instruments

Figure 4.

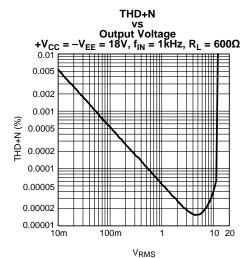


Figure 6.

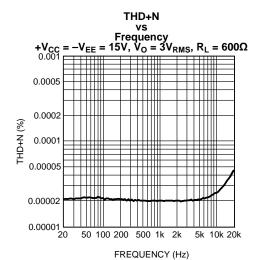


Figure 8.

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Typical Performance Characteristics (continued)

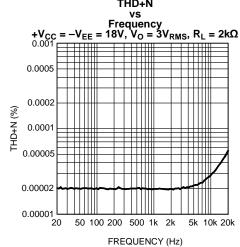


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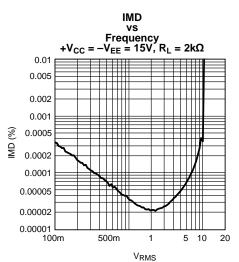
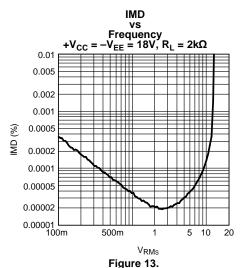


Figure 11.



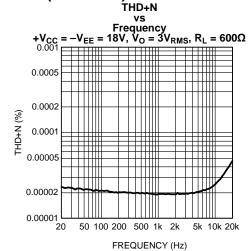


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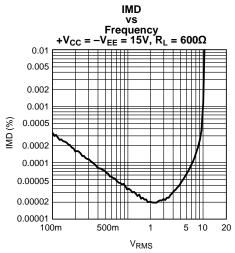


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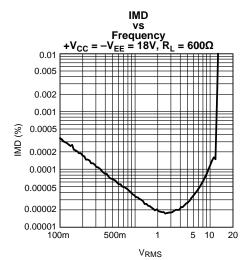


Figure 14.





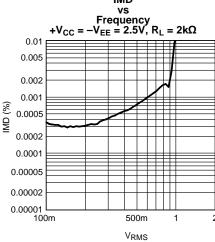


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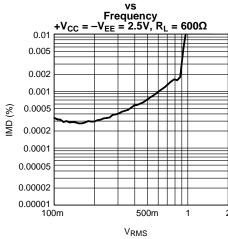
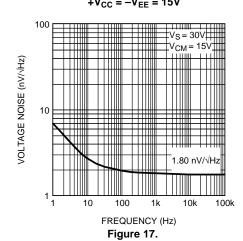


Figure 16.

Voltage Noise Density vs Frequency +V_{CC} = -V_{EE} = 15V



Voltage Noise Density
vs
Frequency
+V_{CC} = -V_{EE} = 18V

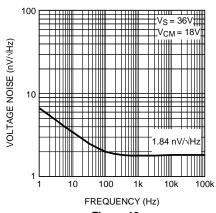
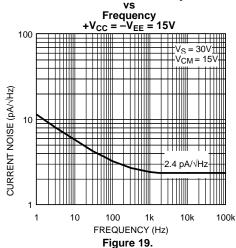
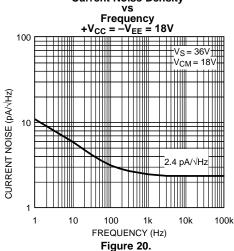


Figure 18.

Current Noise Density









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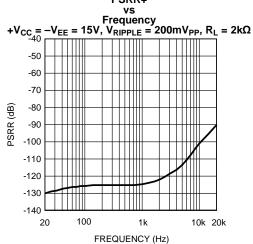


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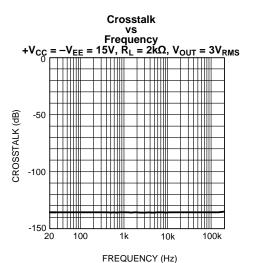
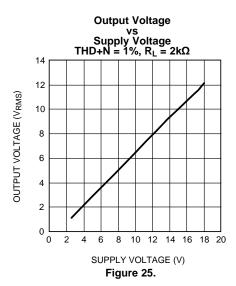
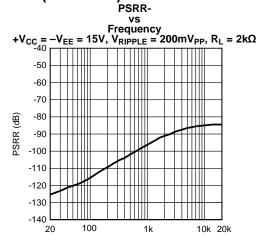


Figure 23.





FREQUENCY (Hz)

Figure 22.

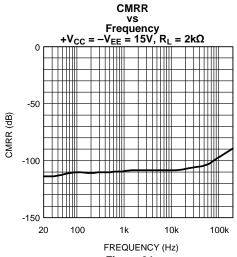


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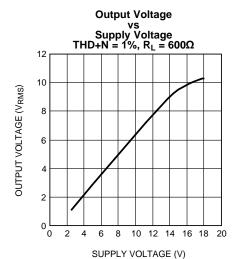


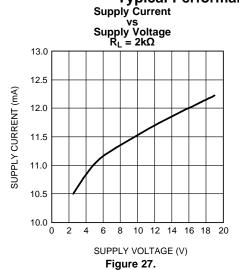
Figure 26.

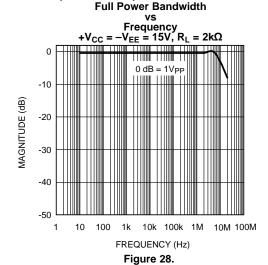
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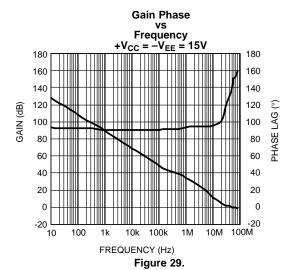
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Typical Performance Characteristics (continued) Full Power Bandwidth







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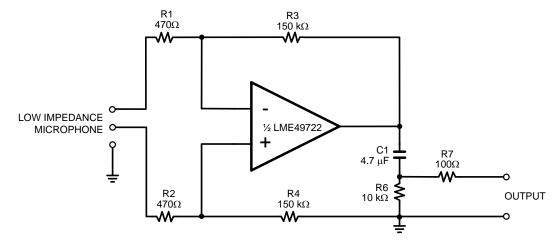


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APPLICATION INFORMATION

APPLICATION HINTS

The LME49722 is a high speed operational amplifier which can operate stably in most of the applications. For the application with gain greater than 2, capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable. Capacitive loads greater than 10pF must be isolated from the output, if the gain value is less than 2. The most straightforward way to do this is to put a resistor (its value $\geq 20\Omega$) in series with the output. The resistor will also prevent unnecessary power dissipation if the output is accidentally shorted.



- Total voltage noise density: $e_{N_{-}total}^{2} \approx e_{N_{-}}^{2} + e_{N_{-}R_{1}}^{2} + e_{N_{-}R_{2}}^{2} = 1.9^{2} + 2 (2.7^{2}),$ then $e_{N_total} = 4.3 \text{ nV}/\sqrt{\text{Hz}}$. For $e_{N_R1} = e_{N_R2} \approx 2.7 \text{ nV}/\sqrt{\text{Hz}}$, if $R1 = R2 \approx 470\Omega$.
- Or total voltage noise = $0.13 \mu V$ input referred in a 1 kHz noise bandwidth.

Figure 30. Low Impedance Microphone Pre-amplifier

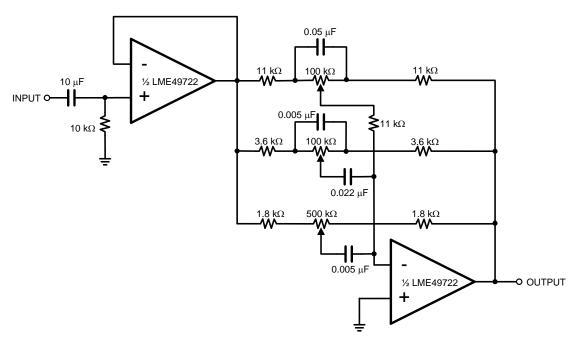


Figure 31. Three-Band Active Tone Control

Product Folder Links: LME49722

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REVISION HISTORY

| Rev | Date | Description |
|-----|----------|------------------|
| 1.0 | 03/27/08 | Initial release. |

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Products Applications

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